NSN 5961-01-123-1540

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View Online at https://aerobasegroup.com/nsn/5961-01-123-1540 **Inclosure Material:** Metal **Overall Length:** 1.499 inches **Overall Height:** 0.555 inches **Overall Width:** 1.000 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 90.0 collector-to-emitter, substaining voltage, base open-circuited all transistor **Current Rating Per Characteristic:** 2.00 amperes source cutoff current all transistor and 10.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 8 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No